

Features:

- High-Side Current Sense Amplifier
- 2.7V to 60V Input Range
- 0.7% Typical Full Scale Accuracy
- Scalable Output Voltage
- SOIC Package

Applications:

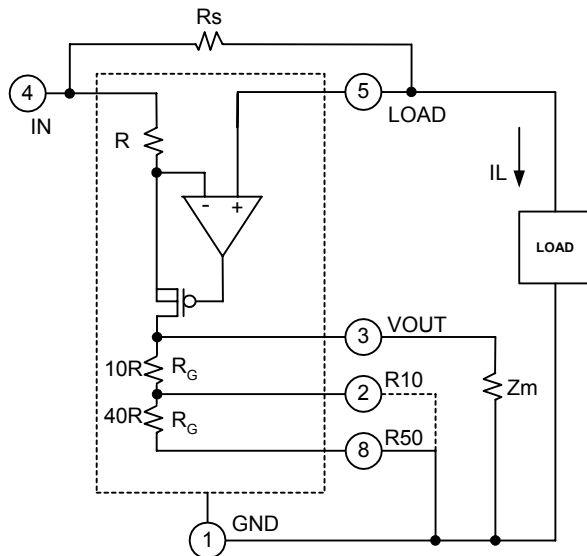
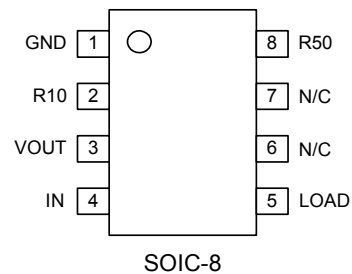
- Power Management Systems
- Smart Battery Packs
- Battery Chargers
- Battery Powered Portable Equipment
- DC Motor Control

General Description

The IXI848A is a precision high side current sense monitor. High side power-line monitoring offers the advantage of allowing the ground plane to remain undisturbed when sensing load currents.

An external sense resistor sets the range of the amplified ground-referenced output monitoring voltage. The output voltage is amplified by a selectable fixed gain of either 10 or 50. With an input voltage range up to 60V, and output gain of up to 50, the IXI848A is designed to address a wide variety of current sense applications.

The IXI848A operates over a temperature range of -40°C to $+85^{\circ}\text{C}$. The IXI848A is available in an 8-Lead SOIC package.

IXI848A Functional Block Diagram and General Application Circuit

IXI848A SOIC PIN Configuration

Ordering Information

Part No.	Description	Package	Quantity
IXI848AS1	High Side Current	SOIC-8	98 (Tube)
XI848AS1T/R	Sense Monitor	SOIC-8	2500 (T&R)

Absolute Maximum Ratings

Parameter	Rating
Voltage to IN (pin 4)	-0.3V to +65V
Differential Input Voltage (V_{SENSE})	$\pm 0.4V$
Input Current to any pin	$\pm 10mA$
Operating Ambient Temp Range	-40°C to +85°C
Operating Junction Temp Range	-40°C to +125°C
θ_{JA}	150°C/W
θ_{JC}	40°C/W
Storage Temp Range	-65°C to +150°C
Lead Temperature (Soldering, 10 sec)	+300°C

Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this data sheet is not implied. Exposure of the device to the absolute maximum ratings for an extended period may degrade the device and affect its reliability.

ESD Warning

ESD (electrostatic discharge) sensitive device. Although the IXI848A feature proprietary ESD protection circuitry, permanent damage may be sustained if subjected to high energy electrostatic discharges. Proper ESD precautions are recommended to avoid performance degradation or loss of functionality.

Electrical Characteristics

$T_A = 25^\circ C$, $V_{IN} = 2.7V$ to $40V$, unless otherwise noted

Parameter	Symbol	Conditions	Min	Typ	Max	Unit	
Operating Voltage Range	V_{IN}		2.7		60	V	
Supply Current	I_{IN}	$V_{IN} = 20V$, $V_{SENSE} = 0V$, $I_{LOAD} = 0A$.065	.130	mA	
Full Scale Sense Voltage	V_{SENSE}			150		mV	
Input Offset Voltage	V_{OS}	$V_{IN} = 12V$	-2.0	± 0.5	2.0	mV	
Full Scale Accuracy		$V_{SENSE} = 100mV$, $V_{IN} = 12V$ $T_A = +25^\circ C$		± 0.7		%	
Total OUT Voltage Error (Note 1, Note 2)		$V_{SENSE} = 100mV$ $V_{IN} = 12V$	$T_A = +25^\circ C$	± 0.7		%	
			$\Delta @ T_A = -40^\circ$ to $+85^\circ C$	± 0.3			
		$V_{SENSE} = 100mV$ $V_{IN} = 40V$	$T_A = +25^\circ C$	± 0.8		%	
			$\Delta @ T_A = -40^\circ$ to $+85^\circ C$	± 0.4			
Gain Accuracy (Note 2)		$V_{SENSE} = 20mV$ to $100mV$ $V_{IN} = 12V$, $40V$	$T_A = +25^\circ C$	± 0.5		%	
			$\Delta @ T_A = -40^\circ$ to $+85^\circ C$	± 0.1			
Gain Setting Resistance	R_G	$V_{IN} = 12V$ $V_{SENSE} = 100mV$	Gain = 10V/V	23	33	43	k Ω
			Gain = 50V/V	115	165	215	k Ω

Note 1: Total OUT voltage error is the sum of gain and offset voltage errors.

Note 2: Production Tested at $T_A = 25^\circ C$.

Pin Description and Configuration

SOIC	Name	Description
1	GND	Ground
2	R10	Connecting R10 to GND, (R50=N/C) selects a VOUT voltage that is 10X the voltage across R _{SENSE} .
3	VOUT	Output voltage proportional to the voltage across R _{SENSE} .
4	IN	Positive supply terminal and power connection for the external Sense Resistor.
5	LOAD	Load-side connection to the external Sense Resistor.
6	N/C	No Connect
7	N/C	No Connect
8	R50	Connecting R50 to GND, (R10=N/C) selects a VOUT voltage that is 50X the voltage across R _{SENSE} .

Detailed Circuit Description

The IXI848A is a precision high side current sense monitor featuring an input voltage range of 2.7V to 60V, and a selectable ground referenced fixed gain output of either 10 or 50.

A small voltage developed across an external sense resistor (R_S), is converted to an amplified ground referenced voltage output at VOUT, (Figure 1). The amplifier's non-inverting input is high impedance making the voltage at that terminal equal to V_{IN} - (I_L) (R_S). The amplifier forces the high impedance inverting terminal to equal the non-inverting input voltage by turning on the P-Channel MOS FET.

As the P-Channel MOS FET is biased on by the amplifier output, current is sourced through R_G (10R or 10R+40R), to produce a voltage equal to V_{IN} - (I_L) (R_S) at the inverting input of the amplifier. This develops a voltage across the inverting input resistor, R that matches the sense voltage across R_S, plus any associated input offset voltage, (V_{IO}). Consequently, the voltage at VOUT corresponds to R_G / R.

$$\text{Output: } V_{OUT} = G [(I_L) (R_S) + V_{IO}]$$

$$\text{Gain: } G = (R_G) (Z_M) / R (R_G (R_G + Z_M))$$

$$R_G = 10R \text{ or } 50R \text{ selectable}$$

Temperature coefficient:

$$\text{(all on-chip resistors) } R = 700\text{ppm} / ^\circ\text{C typical}$$

R_{SENSE} Component Selection

The R_{SENSE} value should be selected such that the voltage across R_{SENSE} is at full-scale for the load current to be monitored. Operating the IXI848A at or near the full-scale sense voltage will minimize

the error component associated with the input offset voltage of the internal op amp.

The IXI848A can be configured to measure a wide selection of currents by using different R_{SENSE} values. Some common values for typical operation of the IXI848A are listed in the following table.

Full-Scale I _L (A)	R _{SENSE} R _S (Ω)	Gain (V/V)	VOUT (V) V _{SENSE} = 150mV
0.15	1.0	10	1.5
1.5	0.1	10	1.5
5	0.01	50	2.5
100	0.001	50	5

Output Impedance

The VOUT output is a current source driving a 33kΩ resistance to ground for a gain of 10, or a 165kΩ resistance to ground for a gain of 50. Output gain is reduced by resistive loading of the VOUT terminal. The impedance of the external monitor load (Z_M) should be chosen high enough to maintain the desired accuracy. Buffering of the VOUT terminal with a high-impedance input stage may be required to minimize output errors.

The following formulas quantify the percent error introduced by output loading:

For a Gain of 10

$$\%_{\text{ERROR}} = 100 [R_{\text{LOAD}} / (33\text{k}\Omega + R_{\text{LOAD}}) - 1]$$

For a Gain of 50

$$\%_{\text{ERROR}} = 100 [R_{\text{LOAD}} / (165\text{k}\Omega + R_{\text{LOAD}}) - 1]$$

R_{LOAD} = the external load applied to VOUT

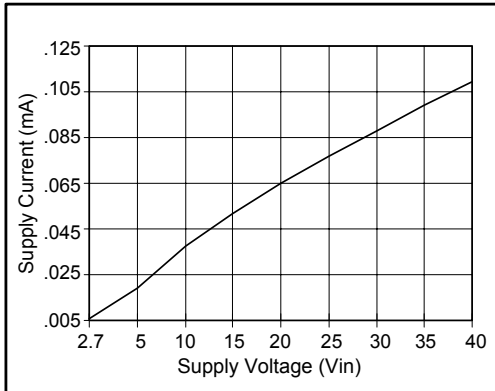
Typical Performance Characteristics


Fig 3. Supply Current vs. Voltage

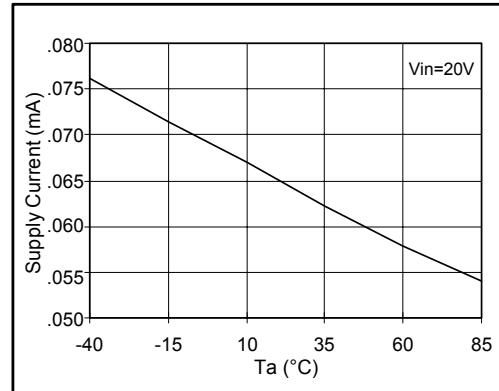


Fig 4. Supply Current vs. Temperature

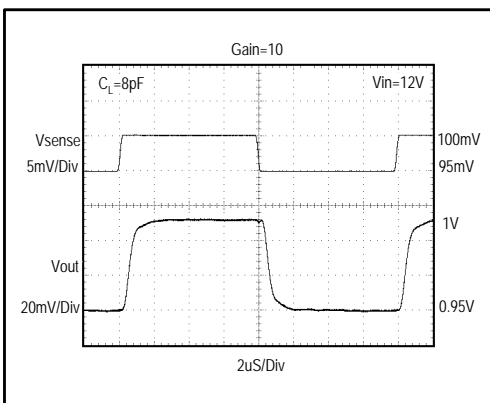


Fig 5. Small Signal Transient Response 10X

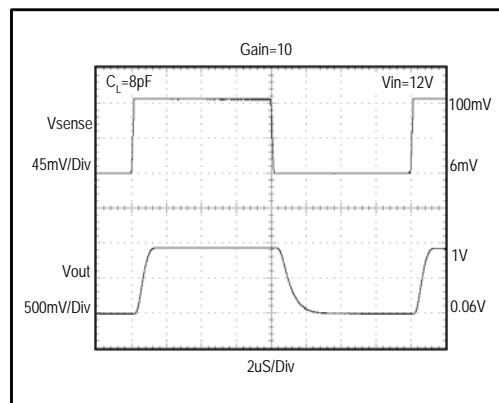


Fig 6. Large Signal Transient Response 10X

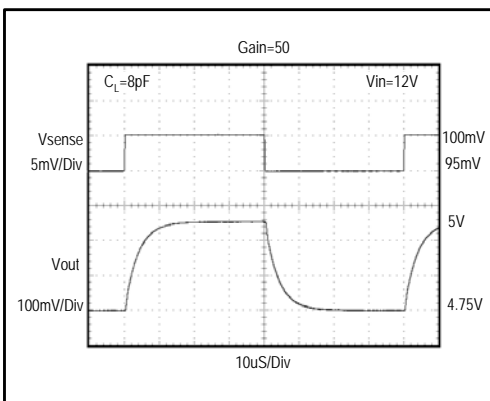


Fig 7. Small Signal Transient Response 50X

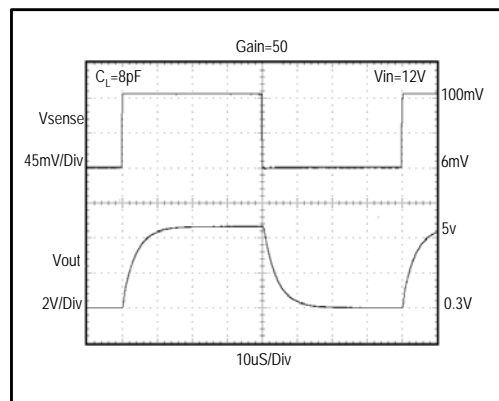
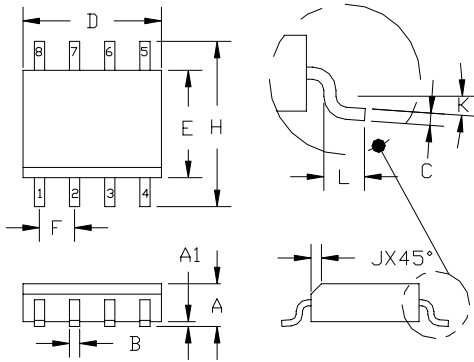


Fig 8. Large Signal Transient Response 50X

Package Outline
8-LEAD SOIC


3. MOLDED PACKAGE SHALL CONFORM TO JEDEC STANDARD CONFIGURATION MS-012 VARIATION AA.

② DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSIONS.

① CONTROLLING DIMENSIONS: MILLIMETERS.

NOTES: (UNLESS OTHERWISE SPECIFIED)

DIM.	DIMENSIONS ①				NOTE
	INCH		MM.		
	MIN.	MAX.	MIN.	MAX.	
A	.0532	.0688	1.35	1.75	----
A1	.0040	.0098	.10	.25	----
B	.013	.020	.33	.51	----
C	.0075	.0098	.19	.25	----
D	.1890	.1968	4.80	5.00	②
E	.1497	.1574	3.80	4.00	②
F	.050	BSC	1.27	BSC	----
H	.2284	.2440	5.80	6.20	----
J	.0099	.0196	.25	.50	----
K	0°	8°	0°	8°	----
L	.016	.050	.40	1.27	----

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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.